

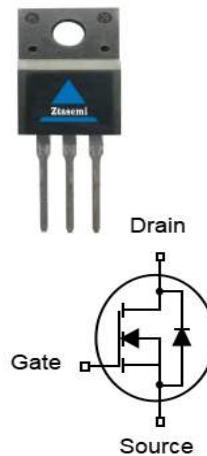


Features

- N-Channel
- Fast Switching
- Improved dv/dt Capability
- 100% EAS Tested

| | | |
|-----------------------------------------|-----|----------|
| V_{DS} | 650 | V |
| $R_{DS(on),TYP}$ @ $V_{GS}=10\text{ V}$ | 1.1 | Ω |
| I_D | 8 | A |

TO-220F



| Part ID | Package Type | Marking | Packing |
|---------|--------------|---------|--------------|
| ZT8N65F | TO-220F | ZT8N65F | 1000pcs/Tape |

Absolute Maximum Ratings $T_A=25^\circ\text{C}$, unless otherwise specified

| Symbol | Parameter | Rating | Unit |
|----------------------------------------------------------------------------------|---------------------------------------------------|-------------------------|---------------------------|
| Common Ratings ($T_c=25^\circ\text{C}$ Unless Otherwise Noted) | | | |
| V_{GS} | Gate-Source Voltage | ± 30 | V |
| $V_{(BR)DSS}$ | Drain-Source Breakdown Voltage | 650 | V |
| T_J | Maximum Junction Temperature | 150 | $^\circ\text{C}$ |
| T_{STG} | Storage Temperature Range | -55 to 150 | $^\circ\text{C}$ |
| I_{DM} | Drain Current-Continuous@ Current-Pulsed (Note 1) | $T_c=25^\circ\text{C}$ | 28 |
| Mounted on Large Heat Sink | | | |
| I_D | Drain Current-Continuous | $T_c=25^\circ\text{C}$ | 8 |
| | | $T_c=100^\circ\text{C}$ | 4.5 |
| P_D | Maximum Power Dissipation | 60 | W |
| $R_{\theta JC}$ | Thermal Resistance-Junction to Case | 2.1 | $^\circ\text{C}/\text{W}$ |
| $R_{\theta JA}$ | Thermal Resistance, Junction-to-Ambient | 62.5 | $^\circ\text{C}/\text{W}$ |
| Drain-Source Avalanche Ratings | | | |
| EAS | Avalanche Energy, Single Pulsed (Note 2) | 245 | mJ |



Electrical Characteristics ($T_J=25^\circ\text{C}$ unless otherwise noted)

| Symbol | Parameter | Condition | Min | Typ | Max | Unit |
|-----------------------------------------------------------------------------------------------------------|-----------------------------------|------------------------------------------------------------------------------------|-----|-----|-----------|---------------|
| Static Electrical Characteristics @ $T_J=25^\circ\text{C}$ (unless otherwise stated) | | | | | | |
| $V_{(\text{BR})\text{DSS}}$ | Drain-Source Breakdown Voltage | $V_{\text{GS}}=0\text{V}, I_D=250\mu\text{A}$ | 650 | -- | -- | V |
| I_{DSS} | Zero Gate Voltage Drain Current | $V_{\text{DS}}=650\text{V}, V_{\text{GS}}=0\text{V}$ | -- | -- | 1 | μA |
| I_{GSS} | Gate-Body Leakage Current | $V_{\text{GS}}=\pm 30\text{V}, V_{\text{DS}}=0\text{V}$ | -- | -- | ± 100 | nA |
| $V_{\text{GS}(\text{th})}$ | Gate Threshold Voltage | $V_{\text{DS}}=V_{\text{GS}}, I_D=250\mu\text{A}$ | 2.0 | -- | 4.0 | V |
| $R_{\text{DS}(\text{on})}$ | Drain-Source On-State Resistance | $V_{\text{GS}}=10\text{V}, I_D=3.5\text{A}$ | -- | 1.1 | 1.35 | Ω |
| Dynamic Electrical Characteristics @ $T_J = 25^\circ\text{C}$ (unless otherwise stated) | | | | | | |
| C_{iss} | Input Capacitance | $V_{\text{DS}}=25\text{V}, V_{\text{GS}}=0\text{V}, f=1\text{MHz}$ | -- | 943 | -- | pF |
| C_{oss} | Output Capacitance | | -- | 106 | -- | pF |
| C_{rss} | Reverse Transfer Capacitance | | -- | 15 | -- | pF |
| Q_g | Total Gate Charge | $V_{\text{DD}}=520\text{V}, I_D=8\text{A}, V_{\text{GS}}=10\text{V}$ | -- | 28 | -- | nC |
| Q_{gs} | Gate-Source Charge | | -- | 4.5 | -- | nC |
| Q_{gd} | Gate-Drain Charge | | -- | 12 | -- | nC |
| Switching Characteristics | | | | | | |
| $T_{\text{d}(\text{on})}$ | Turn-on Delay Time | $V_{\text{DD}}=325\text{V}, I_D=8\text{A}, R_G=25\Omega, V_{\text{GS}}=10\text{V}$ | -- | 19 | -- | ns |
| T_r | Turn-on Rise Time | | -- | 49 | -- | ns |
| $T_{\text{d}(\text{off})}$ | Turn-Off Delay Time | | -- | 89 | -- | ns |
| T_f | Turn-Off Fall Time | | -- | 54 | -- | ns |
| Source- Drain Diode Characteristics@ $T_J = 25^\circ\text{C}$ (unless otherwise stated) | | | | | | |
| I_{SD} | Source-Drain Current (Body Diode) | | -- | -- | 8 | A |
| V_{SD} | Forward on voltage | $I_S=8\text{A}, V_{\text{GS}}=0\text{V}$ | -- | -- | 1.4 | V |
| T_{rr} | Reverse Recovery Time | $T_J=25^\circ\text{C}, I_S=8\text{A}, dI/dt=100\text{A}/\mu\text{s}$ | -- | 400 | -- | ns |
| Q_{rr} | Reverse Recovery Charge | | -- | 3.3 | -- | uC |

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature
2. EAS condition: $T_J = 25^\circ\text{C}$, $V_{\text{DD}} = 50\text{V}$, $V_G = 10\text{V}$, $L = 10\text{mH}$, $I_{\text{AS}} = 8\text{ A}$
3. Pulse Test: Pulse width $\leq 300\mu\text{s}$, Duty Cycle $\leq 1\%$

Typical Performance Characteristics

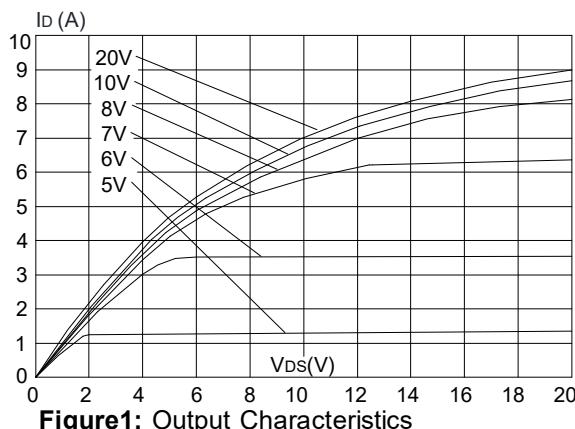


Figure 1: Output Characteristics

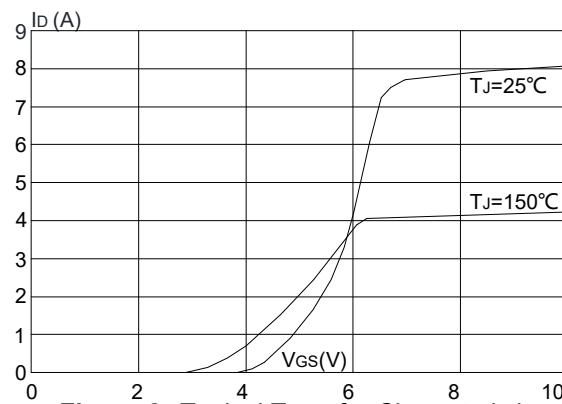


Figure 2: Typical Transfer Characteristics

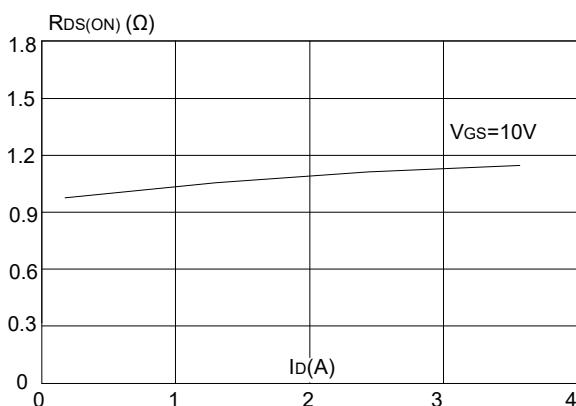


Figure 3: On-resistance vs. Drain Current

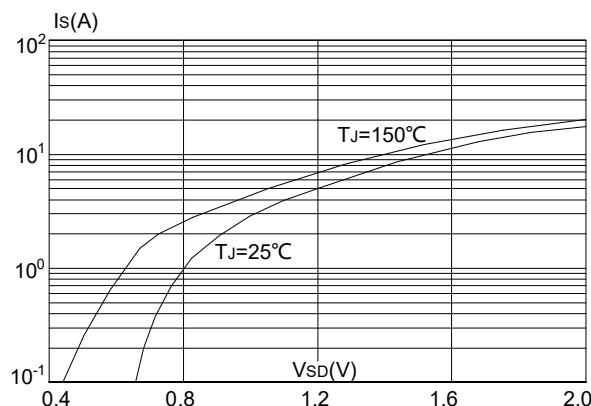


Figure 4: Body Diode Characteristics

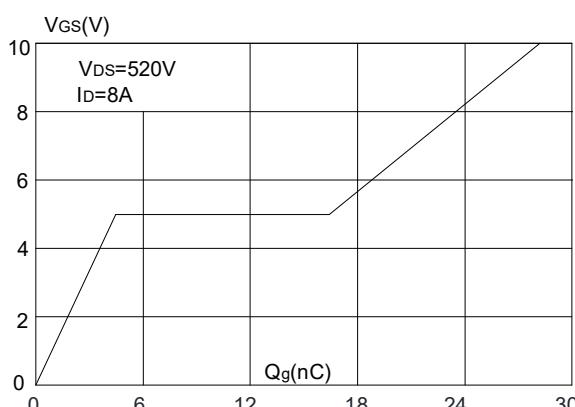


Figure 5: Gate Charge Characteristics

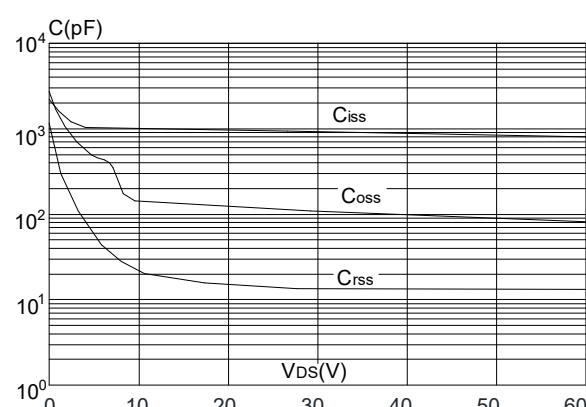


Figure 6: Capacitance Characteristics

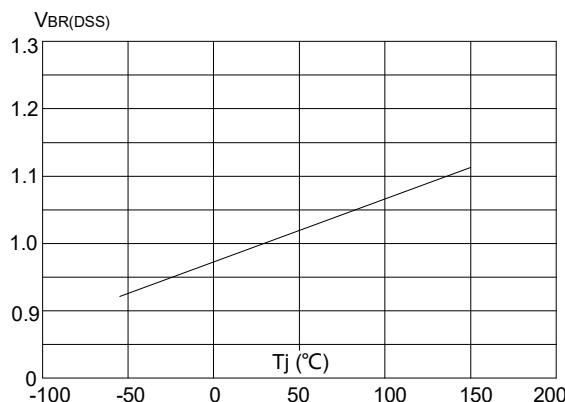


Figure 7: Normalized Breakdown Voltage vs. Junction Temperature

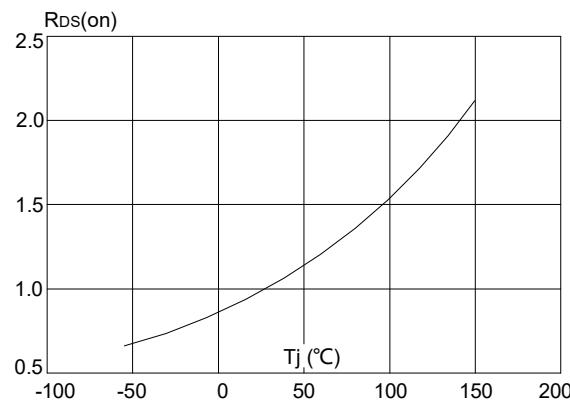


Figure 8: Normalized on Resistance vs. Junction Temperature

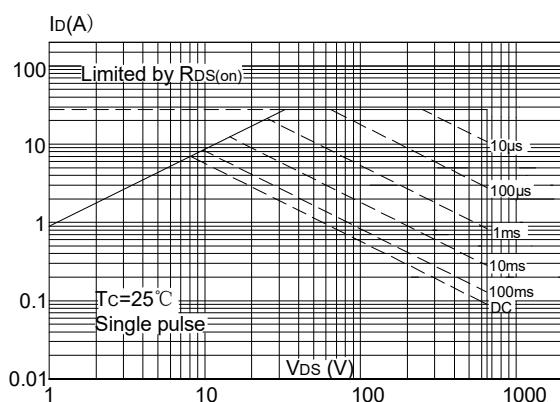


Figure 9: Maximum Safe Operating Area

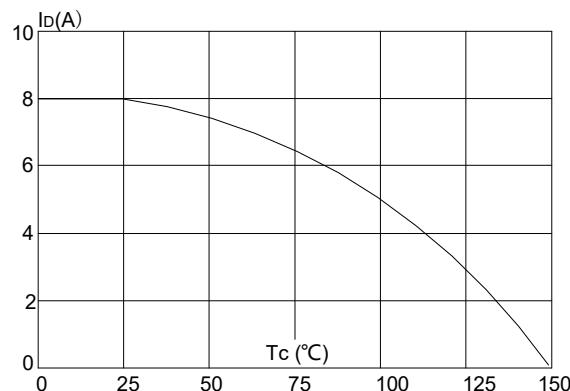


Figure 10: Maximum Continuous Drain Current vs. Case Temperature

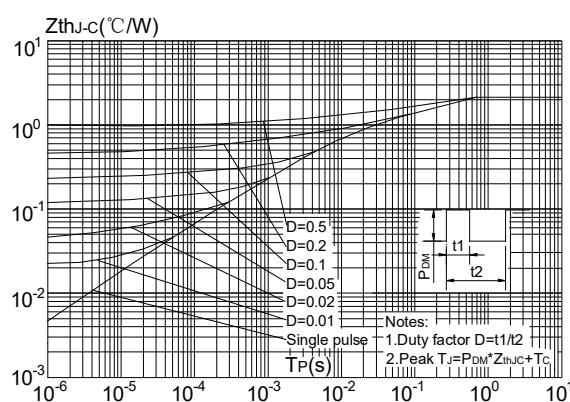


Figure 11: Maximum Effective Transient Thermal Impedance, Junction-to-Case

Test Circuit

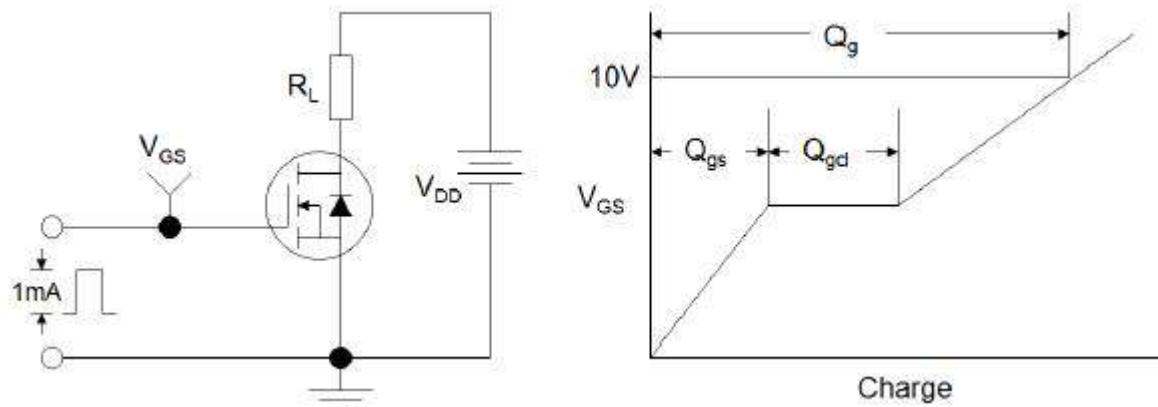


Figure 1: Gate Charge Test Circuit & Waveform

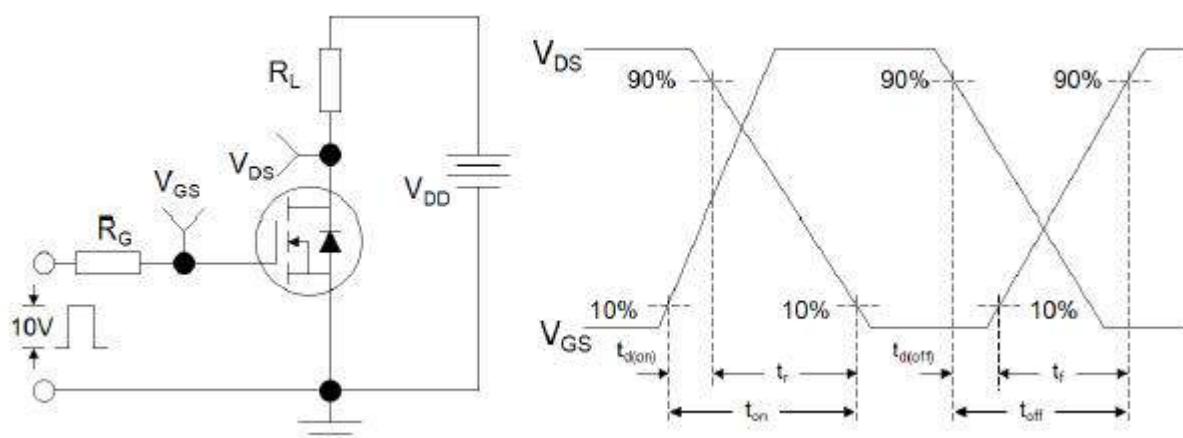


Figure 2: Resistive Switching Test Circuit & Waveforms

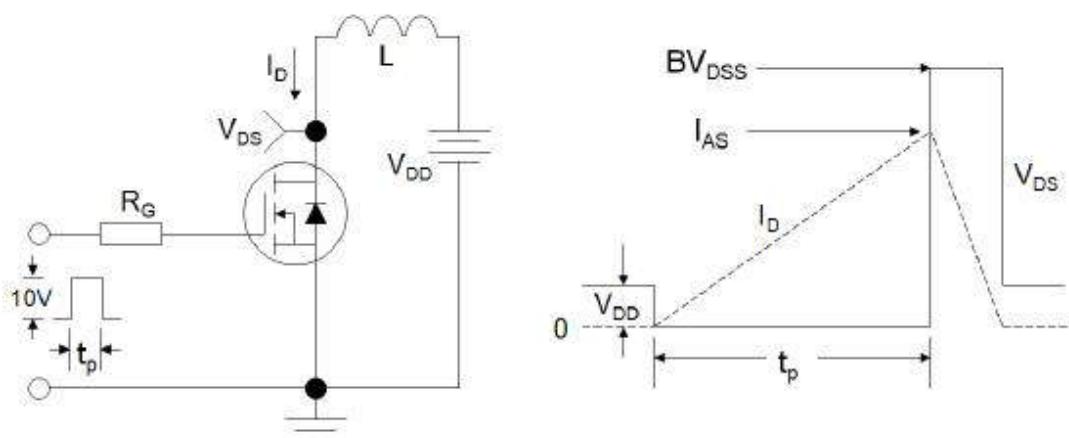
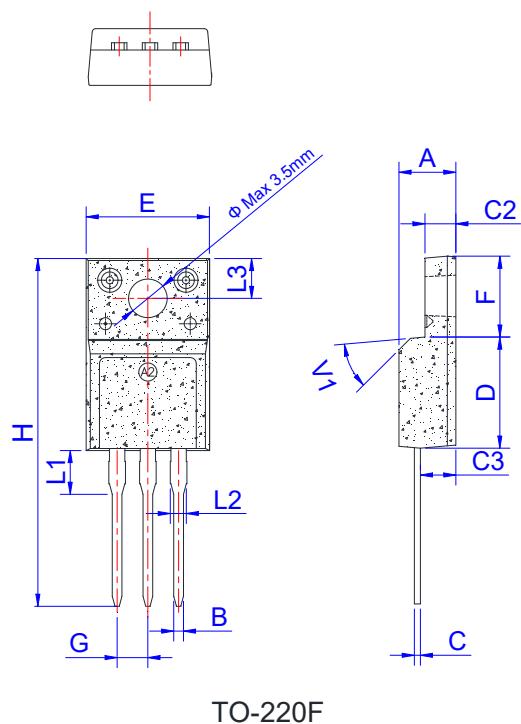


Figure 3: Unclamped Inductive Switching Test Circuit & Waveforms



Mechanical Dimensions for TO-220F



| Ref. | Dimensions | | | | | |
|------|-------------|------|------|--------|-------|-------|
| | Millimeters | | | Inches | | |
| | Min. | Typ. | Max. | Min. | Typ. | Max. |
| A | 4.50 | | 4.90 | 0.177 | | 0.193 |
| B | 0.74 | 0.80 | 0.83 | 0.029 | 0.031 | 0.033 |
| C | 0.47 | | 0.65 | 0.019 | | 0.026 |
| C2 | 2.45 | | 2.75 | 0.096 | | 0.108 |
| C3 | 2.60 | | 3.00 | 0.102 | | 0.118 |
| D | 8.80 | | 9.30 | 0.346 | | 0.366 |
| E | 9.80 | | 10.4 | 0.386 | | 0.410 |
| F | 6.40 | | 6.80 | 0.252 | | 0.268 |
| G | | 2.54 | | | 0.1 | |
| H | 28.0 | | 29.8 | 1.102 | | 1.173 |
| L1 | | 3.63 | | | 0.143 | |
| L2 | 1.14 | | 1.70 | 0.045 | | 0.067 |
| L3 | | 3.30 | | | 0.130 | |
| V1 | | 45° | | | 45° | |

Customer Service

Sales and Service:

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